

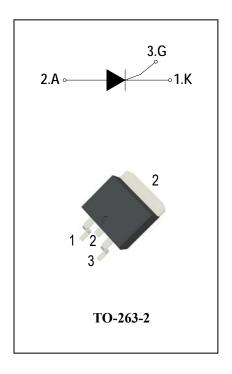
### **SCRs**

## **General Description**

Available either in sensitive or standard gate triggering levels, the 12A SCR series is suitable to fit all modes of control found inapplications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, in-rush current limiting circuits, capacitive discharge ignition, voltage regulation circuits...

#### **Features**

- Repetitive Peak Off-State Voltage: 600V and 800V
- R.M.S On-State Current (IT(RMS)= 12 A)
- These are Pb-Free Devices



## **Absolute Maximum Ratings**

| Symbol              | Items                                  | Conditions  |           | Ratings    | Unit             |  |  |            |    |
|---------------------|--|---|-----------|------------|------------------|--|--|------------|----|
| $V_{DRM}$           | Repetitive Peak Off-State Voltage      | Ti=25°C   | ADT12A60G | 600        | V                |  |  |            |    |
| $V_{RRM}$           | Repetitive peak reverse voltage        | Tj=25°C   | ADT12A80G | 800        | V                |  |  |            |    |
| I <sub>T(AV)</sub>  | Average On-State Current               | Half Sine Wave , Tc = 110°C                                   |           | 10         | А                |  |  |            |    |
| I <sub>T(RMS)</sub> | R.M.S On-State Current                 | Half Sine Wave , Tc = 110°C                                   |           | 12         | Α                |  |  |            |    |
| I <sub>TSM</sub>    | Surge On-State Current                 | 1/2 Cycle, Sine Wave Non-Repetitive,<br>tp=10ms(50Hz)Tj =25°C |           | 190        | А                |  |  |            |    |
| I <sup>2</sup> t    | I <sup>2</sup> t for Fusing            | Tj =25°C,tp =10ms   |           | 98         | A <sup>2</sup> S |  |  |            |    |
| P <sub>GM</sub>     | Forward Peak Gate Power Dissipation    | Tj =125°C, Pulse Width ≤ 20 <i>μ</i> s                        |           | 5          | W                |  |  |            |    |
| $P_{G(AV)}$         | Forward Average Gate Power Dissipation | Tj =25°C, tp =10ms  |           | 1          | W                |  |  |            |    |
| I <sub>GM</sub>     | Peak Gate Current                      | Tj =125°C, Pulse Width ≤ 20μs                                 |           | 4          | Α                |  |  |            |    |
| Tj                  | Operating Junction Temperature         |   |           | - 40 ~ 125 | °C               |  |  |            |    |
| T <sub>STG</sub>    | Storage Temperature                    |   |           |            |                  |  |  | - 40 ~ 150 | °C |





## ADT12A60G/80G

## **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

| Symbol               | Items  | Conditions                                  |         | ADT12A60G/80G |     | Unit  |       |  |
|----------------------|--|---|---------|---------------|-----|-------|-------|--|
|                      |  |   |         | Т             | s   | Blank |       |  |
|                      |  | $V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$      |         |               | 5   |       | uA    |  |
| I <sub>DRM</sub>     | Peak Forward Reverse                                 | Tj = 25°C                                   | Mov     | 5             |     |       | G., 1 |  |
| I <sub>RRM</sub>     | Blocking Current                                     | $V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$      | Max.    | 2             |     | mA    |       |  |
|                      |  | Tj = 125°C                                  |         | 2             |     |       | III ( |  |
| V <sub>TM</sub>      | Peak On-State Voltage                                | $I_{TM} = 24A$ , $t_p = 380 \mu s$          | Max.    | 1.55          |     | V     |       |  |
| $V_{GD}$             | Non-Trigger Gate Voltage                             | $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ | Min.    | Min           |     |       | V     |  |
| V GD                 | Non-mgger Gate Voltage                               | $R_{GK} = 1K\Omega$ $Tj = 125$ °C           | IVIIII. | 0.2           |     |       | V     |  |
| $V_{GT}$             | Gate Trigger Voltage                                 | V 40V B 200                                 | Max.    | 1.5           |     | V     |       |  |
| I <sub>GT</sub>      | Gate Trigger Current                                 | $V_D = 12V , R_L = 33\Omega$                | Max.    | 0.2           | 15  | 30    | mA    |  |
| I <sub>H</sub>       | Holding Current                                      | $I_T = 0.5A$ $R_{GK} = 1K\Omega$            | Max.    | 5             | 30  | 40    | mA    |  |
| ΙL                   | Latching Current                                     | $I_G = 1.2 I_{GT} R_{GK} = 1 K\Omega$       | Max.    | 7             | 50  | 60    | mA    |  |
| ط/ (/طلا             | Critical Rate of Rise of                             | $V_D = 2/3V_{DRM}$ gate open                | Min     | 200 500       | 500 | 000   | \//   |  |
| dV/dt                | Off-State Voltage                                    | $R_{GK} = 1K\Omega$ Tj = 125°C              | Min.    | 200           | 500 | 600   | V/µs  |  |
| R <sub>th(j-c)</sub> | Junction to case (AC)                                |   | Max.    | 1.3           |     | °C/W  |       |  |
| R <sub>th(j-a)</sub> | Junction to ambient(Copper surface under tab:S=1cm²) |   | Max.    | 45            |     |       | °C/W  |  |

FIG.2: Average on-state current VS Allowable

# **ADV**

FIG.1: Maximum average power dissipation (Single phase half wave)

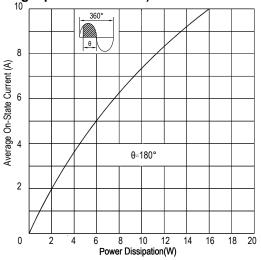


FIG.3: Gate trigger current VS Junction temperature

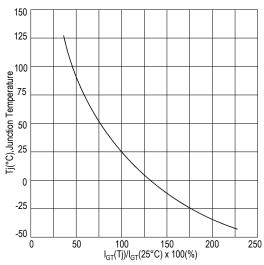


FIG.5: On-state characteristics(Max)

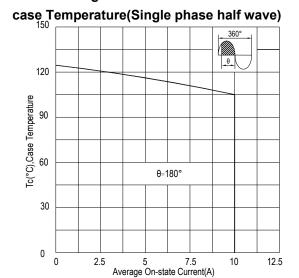
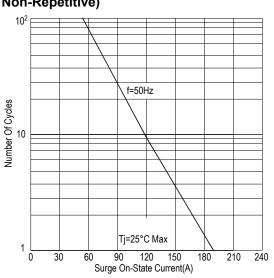
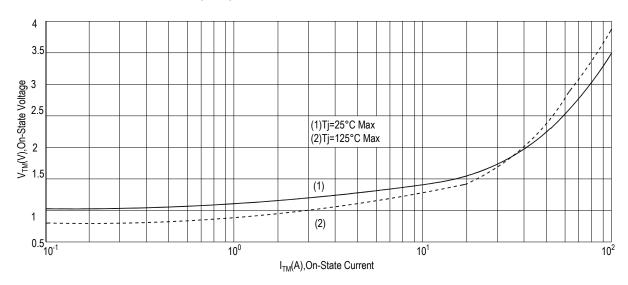


FIG.4: Rated surge on-state current (Non-Repetitive)







## ADT12A60G/80G

FIG.6:Holding current and Latching current VS Junction temperature

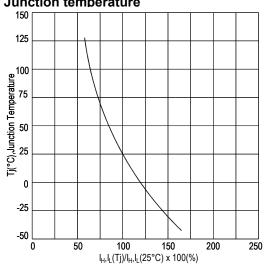


FIG.8: Gate trigger current VS Junction temperature for type T gate triggering

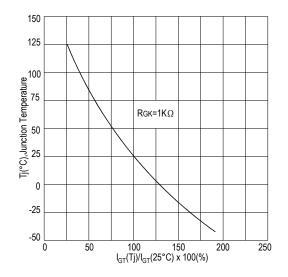


FIG.7: Gate trigger voltage VS Junction

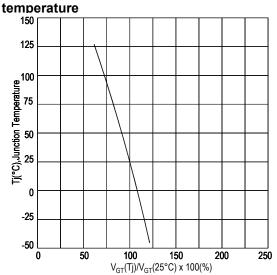
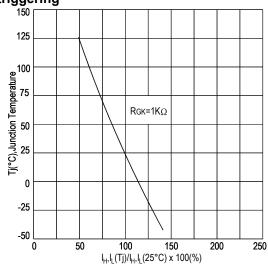


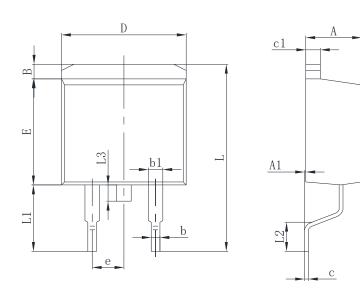
FIG.8:Holding current and Latching current
VS Junction temperature for type T gate
triggering





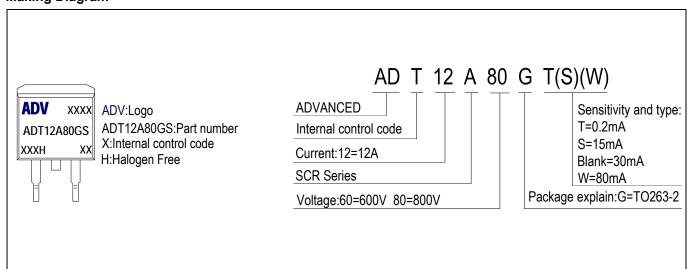
## PACKAGE MECHANICAL DATA

#### **TO-263-2 Package Dimension**



| Cumb | Dimer          | nsions | Dimensions |       |  |  |
|------|----------------|--------|------------|-------|--|--|
| Symb | In Millimeters |        | In Inches  |       |  |  |
| OI   | Min            | Max    | Min        | Max   |  |  |
| Α    | 4.400          | 4.800  | 0.173      | 0.189 |  |  |
| A1   | 0.000          | 0.250  | 0.000      | 0.010 |  |  |
| В    | 1.170          | 1.600  | 0.046      | 0.063 |  |  |
| b    | 0.710          | 0.910  | 0.028      | 0.036 |  |  |
| b1   | 1.050          | 1.450  | 0.041      | 0.057 |  |  |
| С    | 0.280          | 0.550  | 0.011      | 0.022 |  |  |
| c1   | 1.170          | 1.370  | 0.046      | 0.054 |  |  |
| D    | 9.900          | 10.350 | 0.390      | 0.407 |  |  |
| E    | 8.500          | 9.600  | 0.370      | 0.334 |  |  |
| е    | 2.540          | ) TYP  | 0.100 TYP  |       |  |  |
| L    | 14.700         | 15.800 | 0.579      | 0.622 |  |  |
| L1   | 3.800          | 5.480  | 0.149      | 0.215 |  |  |
| L2   | 2.050          | 2.950  | 0.081      | 0.116 |  |  |
| L3   |                | 1.750  |            | 0.069 |  |  |

### **Making Diagram**



### **Ordering information**

| Part number  | Package  | Marking    | Packing       | Quantity |  |
|--|----------|------------|---------------|----------|--|
| ADT12A60G#   | TO-263-2 | ADT12A60G# | Tube          | 50pcs    |  |
| ADTIZA00G#   |          |            | Embossed tape | 800pcs   |  |
| ADT10A000#   | TO-263-2 | ADT12A80G# | Tube          | 50pcs    |  |
| ADT12A80G#   |          |            | Embossed tape | 800pcs   |  |
| Note:# = Gate Trigger Current Sensitivity and type |          |            |               |          |  |



## ADT12A60G/80G

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